

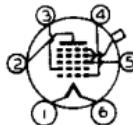


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PENTAGRID CONVERTER

Filament	Coated	
Voltage	2.0	d-c volts
Current	0.12	amp.
Direct Interelectrode Capacitances:		
Grid #4 to Plate	0.30*	μμf
Grid #4 to Grid #2	0.30*	μμf
Grid #4 to Grid #1	0.15*	μμf
Grid #1 to Grid #2	1.5	μμf
Grid #4 to All Other Electrodes (R-F Input)	10	μμf
Grid #2 to All Other Electrodes (osc. Output)	6	μμf
Grid #1 to All Other Electrodes (osc. Input)	6	μμf
Plate to All Other Electrodes (Mixer Output)	10	μμf
Overall Length	4-9/32"	to 4-17/32"
Maximum Diameter		1-9/16"
Bulb		ST-12
Cap		Small Metal
Base		Small 6-Pin
Pin 1 - Filament +		
Pin 2 - Plate		
Pin 3 - Grid #2		
Pin 4 - Grid #1		
Mounting Position	BOTTOM VIEW (6L)	Vertical [◊]



Pin 5 - Grids #3 & #5
Pin 6 - Filament -
Cap - Grid #4

CONVERTER SERVICE

Plate Voltage	180	max. volts
Screen (Grids #3 & #5) Voltage	67.5	max. volts
Screen Supply Voltage	180	max. volts
Anode-Grid (Grid #2) Voltage	135	max. volts
Anode-Grid Supply Voltage	180	max. volts
Control-Grid (Grid #4) Voltage	0 min.	volts
Plate Dissipation	0.3	max. watt
Screen Dissipation	0.2	max. watt
Anode-Grid Dissipation	0.4	max. watt
Total Cathode Current	9	max. ma.
Typical Operation:		
Filament	2.0	d-c volts
Plate	135	volts
Screen	67.5	volts
Anode-Grid Supply	135 [▲]	volts
Control Grid	-3	volts
Osc.-Grid (Grid #1) Resistor	50000	ohms
Plate Res. (approx.)	0.6	megohm
Conversion Transcond.	300	μμhos
Convert. Transcond. (approx.) with grid #4 bias of -14 volts	4	μμhos
Plate Cur.	1.5	ma.
Screen Cur.	2.5	ma.
Anode-Grid Cur.	3.1	ma.
Oscillator-Grid Cur.	0.2	ma.
Total Cathode Cur.	7.1	ma.

NOTE: The transconductance of the oscillator portion (not oscillating) is 1050 micromhos under the following conditions: plate volts, 180; screen volts, 67.5; anode-grid volts, 135; and oscillator-grid volts, 0.

* With shield-can connected to negative filament terminal.

◊ Horizontal operation permitted if pins 1 and 6 are in vertical plane.

▲ Applied through properly bypassed 20000-ohm voltage-dropping resistor.

A Typical Pentagrid Converter Circuit is shown under Type 1A6.

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OPERATION CHARACTERISTICS

 $E_f = 2.0$ VOLTS D.C.SCREEN (GRIDS N^o3 & N^o5) VOLTS = 67.5OSCILLATOR GRID (GRID N^o1) RESISTOR - OHMS = 50000

OSCILLATOR GRID CURRENT - MILLIAMPERES = 0.2

CURVE PLATE VOLTS ANODE-GRID (GRID N^o2) SUPPLY VOLTS*

—	135	135
—	180	180

*APPLIED THROUGH 20000-OHM DROPPING RESISTOR

